

# An ADC-Free Adaptive Interface Circuit of Resistive Sensor for Electronic Nose System

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**Abstract**—The initial resistance of chemiresistive gas sensors could be affected by temperature, humidity, and background odors. In a sensing system, the traditional interface circuit always requires an ADC to convert analog signal to digital signal. In this paper, we propose an ADC-free adaptive interface circuit for a resistive gas sensor to read sensor signal and cancel the baseline drift. Furthermore, methanol was used to test the proposed interface circuit, which was connected with a FIGARO® gas sensor. This circuit was fabricated by TSMC 0.18 $\mu\text{m}$  CMOS process, and consumed 86.41 $\mu\text{W}$  under 1V supply voltage.

## I. INTRODUCTION

Olfaction is one of the human's five senses. However, many odors are not suitable for human to smell, such as poisonous and exhausted gases. In addition, humans have olfactory fatigue because of long time smelling, and olfaction differs from person to person. Nowadays, there are several researches on the electronic nose (E-nose) system. An E-nose system has various advantages including small size, low cost, low power, quantization of olfaction, the ability of long time smelling without olfactory fatigue, and the capability of being exposed to dangerous gases. Therefore, it can be applied to quality control of foods [1, 2], environmental monitoring, pollution measurement and disease diagnosis [3-5], etc.

E-nose system is a biomimetic system that mimics the mammalian olfaction, which has the ability to differentiate and classify various chemical odors. Fig. 1 shows the E-nose system and mammalian sense of smell. Gas sensor array, signal acquisition circuit and pattern recognition system in E-nose system are corresponding to olfactory cells, olfactory neurons and cerebrum in the mammalian sense of smell, respectively. Because one sensor could not detect one specific gas, a gas sensor array is required to generate a unique pattern for gas identification. There are two kinds of the conductive gas sensors, metal oxide sensor (MOS) [6,7] and conducting polymer sensor [8,9]. Metal oxide sensor has the advantages of high sensitivity (about a few ppm), long lifetime and robust, and it has been widely used. However, it has to operate at high temperature (200 $^{\circ}\text{C}$ ~400 $^{\circ}\text{C}$ ), which needs a heater and consumes large power. On the other hand, the conducting polymer sensor has the advantages of working at room temperature, high sensitivity (also about a few ppm), and its readout circuit is simple, which would be more suitable for portable devices.

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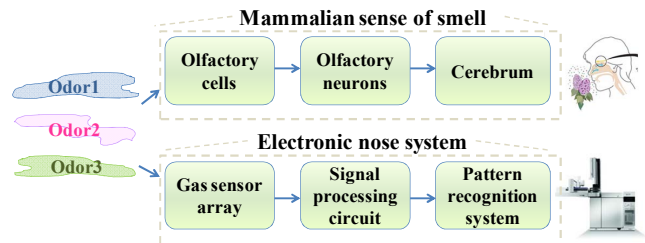


Figure 1. E-nose system and mammalian sense of olfaction.

The sensing materials of conducting polymer sensors are composed of conductive carbon black and insulating polymers, which swell reversibly and change the resistance as exposed to odors. However, the sensor resistance could be easily affected by temperature, humidity, and background odors. In addition, the resistances of each sensor in the sensor array are not the same after the deposition of different sensing materials. Therefore, an adaptive interface circuit is required to cancel the baseline drift and read the sensor signal. A number of interface circuits for resistive gas sensors have recently been proposed [10-12]. Most of them convert the sensor signal into voltage, and then deliver the voltage to an analog-to-digital converter (ADC) before further delivered to the pattern recognition system. In this paper, we propose an ADC-free adaptive interface circuit which cancels the baseline drift and converts sensor signal into digital code, so the sensor signal can be directly delivered to the digital processing stage without an ADC. Section II depicts the proposed ADC-free adaptive interface circuit connected with an integrated gas sensor in our E-nose chip. Section III shows the measurement results, and finally, Section IV provides our conclusion.

## II. ARCHITECTURE DESCRIPTION

Fig. 2 shows the structure of the proposed application-specific integrated circuit (ASIC) for the E-nose system. It contains an integrated gas sensor and an ADC-free adaptive interface circuit. We used top metal to form an interdigitated electrode of the integrated gas sensor. We could deposit the sensing material on the interdigitated electrode to form the on-chip integrated gas sensor, and it was directly connected with the adaptive interface using the remaining metal layers. Due to the integration of the gas sensor and the adaptive interface circuit on the same chip, it achieves several advantages such as small size, low cost, low power and low noise. To verify our work, we have tested one channel interface circuit connected with an integrated gas sensor. In the future, multi-channel interface circuits connected with an integrated gas sensor array will be realized to generate a unique pattern for gas identification.

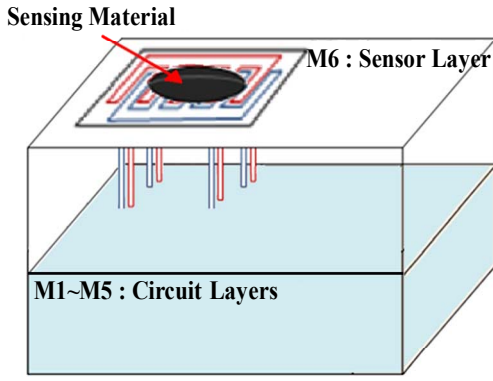


Figure 2. The structure of our E-nose chip.

### A. Integrated Gas Sensor

Fig. 3 shows the layout of the integrated gas sensor. The top metal (Metal 6) of the TSMC 0.18 $\mu\text{m}$  CMOS 1P6M process was used to form the interdigitated electrodes, and the PAD mask was used to define the deposition region of the sensing material. The silicon nitride protective layer would be removed as it was defined by the PAD mask. In this way, the electrodes could directly contact with the sensing materials. Compared to a two-lead electrode structure, an interdigitated electrode structure ensured that the sensing materials uniformly distributed between the positive and negative electrodes, so they would successfully form a conductive path. The sensing area of the sensor is 250  $\mu\text{m}$   $\times$  320  $\mu\text{m}$ , the width of the electrode is 16 $\mu\text{m}$ , and the distance between the two electrodes is 10 $\mu\text{m}$ .

### B. Adaptive Interface Circuit

An adaptive interface circuit not only reads the sensor signal, but also eliminates the baseline drift caused by the temperature, humidity and background odors. Fig. 4 shows the block diagram of the proposed ADC-free adaptive interface circuit, which is composed of a comparator, an 8-bit UP/ $\overline{\text{DN}}$  counter, and an 8-bit digital-to-analog converter (DAC). The output current of DAC ( $I_{\text{DAC}}$ ) biases the sensor, and the magnitude of  $I_{\text{DAC}}$  is controlled by the output of UP/ $\overline{\text{DN}}$  counter ( $D_{\text{out}}$ ). Through the feedback loop, the ADC-free adaptive interface circuit could bias the sensor to a pre-set voltage regardless of the initial resistance of the gas sensor, and then read the sensor signal.

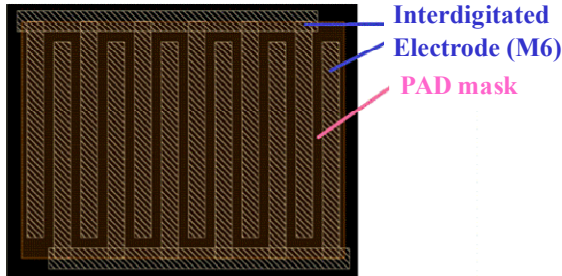


Figure 3. Layout of the integrated gas sensor. The sensing area is 250  $\mu\text{m}$   $\times$  320  $\mu\text{m}$ , the width of the electrode is 16 $\mu\text{m}$ , and the distance between the two electrodes is 10 $\mu\text{m}$ .

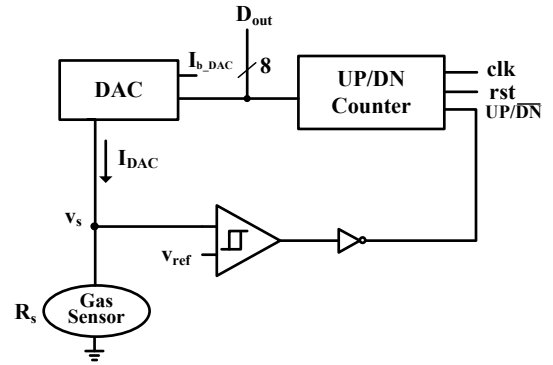


Figure 4. The block diagram of the proposed adaptive interface circuit

This circuit works in the following two mode: 1) adaptive mode: bias the sensor to a proper reference voltage  $V_{\text{ref}}$ , and 2) sensing mode: convert the sensor signal into digital code  $D_{\text{out}}$ . The operation procedures are as follows: 1) Reset the UP/ $\overline{\text{DN}}$  counter to reset  $D_{\text{out}}$  to zero, the circuit is in the adaptive mode. Because the output of the comparator is low, the UP/ $\overline{\text{DN}}$  counter counts up to increase  $I_{\text{DAC}}$ . 2) As the sensor voltage  $V_s$  reaches  $V_{\text{ref}}$ , the output of the comparator changes state from low to high, and then the UP/ $\overline{\text{DN}}$  counter counts down. 3) As  $V_s$  is smaller than  $V_{\text{ref}}$ , the output of the comparator changes state from high to low, and then the UP/ $\overline{\text{DN}}$  counter counts up again. After that, the circuit enters into sensing mode and is ready to sense gas. In sensing mode, the circuit repeats procedure 2) and 3), and  $V_s$  maintains at  $V_{\text{ref}}$  until the next reset signal.

In sensing mode,  $R_s$  changes when the gas sensor reacts with the test gas, which comes out different  $D_{\text{out}}$  to adapt  $I_{\text{DAC}}$  for maintaining  $V_s$  equal to  $V_{\text{ref}}$ . Because  $D_{\text{out}}$  is proportional to  $I_{\text{DAC}}$ , the relationship between  $D_{\text{out}}$  and  $R_s$  is shown in equation (1), where  $I_{b\_DAC}$  is the unit current of DAC. Suppose  $R_1$  is the initial sensor resistance and  $D_{\text{out}1}$  is the output of UP/ $\overline{\text{DN}}$  counter at the end of the adaptive mode. In the sensing mode, the sensor resistance and the output of UP/ $\overline{\text{DN}}$  counter are assumed  $R_2$  and  $D_{\text{out}2}$ , respectively.  $\Delta R$  and  $\Delta D_{\text{out}}$  imply the change of resistance and the change of  $D_{\text{out}}$ , respectively. Therefore, the relationship between  $R_1$ ,  $R_2$  and  $\Delta R$  is shown in equation (2), and the relationship between  $D_{\text{out}1}$ ,  $D_{\text{out}2}$  and  $\Delta D_{\text{out}}$  is shown in equation (3). According to equation (1) ~ (3), the percentage change of resistance  $\Delta R/R_1$  can be derived as  $\Delta D_{\text{out}} / D_{\text{out}1}$ , as equation (4).

$$V_s = V_{\text{ref}} = I_{\text{DAC}} \times R_s = I_{b\_DAC} \times D_{\text{out}} \times R_s \quad (1)$$

$$R_2 = R_1 + \Delta R \quad (2)$$

$$D_{\text{out}2} = D_{\text{out}1} - \Delta D_{\text{out}} \quad (3)$$

$$\Delta R/R_1 = \Delta D_{\text{out}}/D_{\text{out}1} \quad (4)$$

In reality, the response time of gas sensor is always a few seconds. In the simulation, the response time of gas sensor was assumed only a few milliseconds, and the integrated gas sensor was replaced by a resistor. Fig. 5 shows the post-layout simulation results, where  $R_1=10\text{K}\Omega$ ,  $V_{\text{ref}}=0.7\text{V}$  and  $\Delta R=10\text{K}\Omega$  (Usually the maximum percentage change of resistance  $\Delta R/R_1$  is 100%). The blue line, red line and green line correspond to  $R_s$ ,  $V_s$  and  $D_{\text{out}}$ , respectively. At  $t=0\text{sec}$ , the UP/ $\overline{\text{DN}}$  counter was reset, the circuit was in the adaptive mode.

At  $t=23.4\text{ms}$ ,  $V_s$  reached  $V_{\text{ref}}=0.7\text{V}$  and  $D_{\text{out}}$  was 234, and then the circuit entered into the sensing mode. At  $t=30\text{ms}$ , suppose the gas sensor was exposed to an odor. The sensor resistance started increasing, and the counter also started counting down to decrease  $I_{\text{DAC}}$  for keeping  $V_s=V_{\text{ref}}$ . At  $t=65\text{ms}$ , the sensor resistance saturated to  $20\text{K}\Omega$ , and  $D_{\text{out}}$  was 117. At  $t=70\text{ms}$ , the odor was flushed out. The sensor resistance started decreasing and the counter also started counting up for keeping  $V_s=V_{\text{ref}}$ .

According to the above simulation results, Fig. 6 shows that  $\Delta D_{\text{out}}/D_{\text{out}2}$  is proportional to  $\Delta R/R_1$ . Consequently,  $R_s$  could be obtained from  $D_{\text{out}}$ , and equation (4) depicts the relationship between  $R_s$  and  $D_{\text{out}}$ . By this adaptive interface circuit,  $D_{\text{out}}$  could be directly delivered to the digital signal processing stage without an ADC, reducing the chip area, complexity and power consumption of the E-nose system. The adaptive interface circuit was fabricated by TSMC  $0.18\mu\text{m}$  CMOS process and operated under  $1\text{V}$  supply voltage. Fig. 7 shows the chip photo, and the integrated gas sensor was on the top of the adaptive interface circuit.

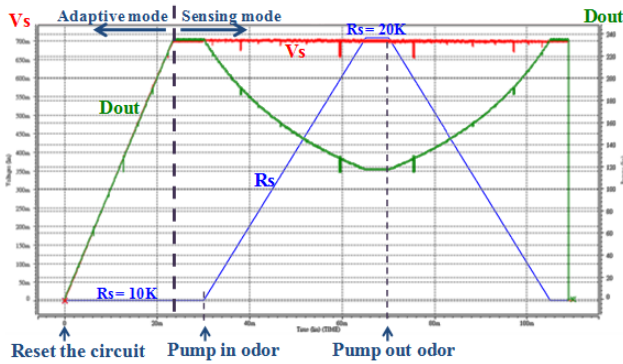


Figure 5. Post-layout simulation when initial resistance of gas sensor  $R_1=10\text{K}\Omega$ ,  $V_{\text{ref}}=0.7\text{V}$  and  $\Delta R=10\text{K}\Omega$ .

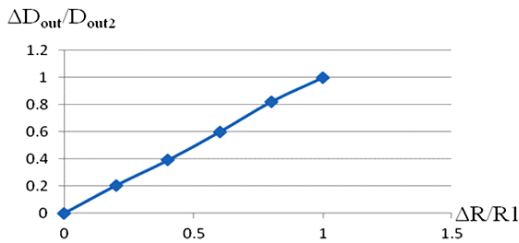


Figure 6.  $\Delta D_{\text{out}}/D_{\text{out}2}$  versus  $\Delta R/R_1$  according to the simulation result as  $R_s$  reacts from  $10\text{K}\Omega$  to  $20\text{K}\Omega$

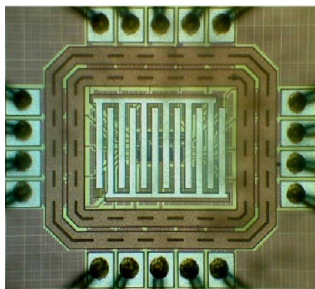


Figure 7. The chip photo of the integrated gas sensor and the proposed adaptive interface circuit.

### III. MEASUREMENT RESULT

Before depositing the sensing material, the two electrodes were open, so the gas sensor ( $R_s$ ) could be directly replaced by an off-chip resistor. Fig. 8 shows the measurement results of  $D_{\text{out}}$  versus  $R_s$  as  $V_{\text{ref}} = 650\text{mV}$  and the bias current of DAC  $I_{\text{b\_DAC}} = 1\mu\text{A}$ , where  $R_s$  was replaced by a variable resistor varying from  $2.5\text{K}\Omega$  to  $80\text{K}\Omega$ . Fig. 9 shows the measurement results of  $D_{\text{out}}$  versus  $R_s$  as  $V_{\text{ref}} = 700\text{mV}$  and the bias current of DAC  $I_{\text{b\_DAC}} = 330\text{nA}$ , where variable resistor  $R_s$  varied from  $10\text{K}\Omega$  to  $165\text{K}\Omega$ . Table 1 shows the summary of the chip specification.

For gas experiments, the adaptive interface circuit was connected with a commercial FIGARO<sup>®</sup> TGS-2610 gas sensor to replace the integrated gas sensor. FIGARO<sup>®</sup> TGS-2610 gas sensor is a metal oxide gas sensor, and the sensor resistance reduces when it is exposed to odors, opposite to the conducting polymer gas sensor. However, the same relationship between  $D_{\text{out}}$  and  $R_s$  could be derived.

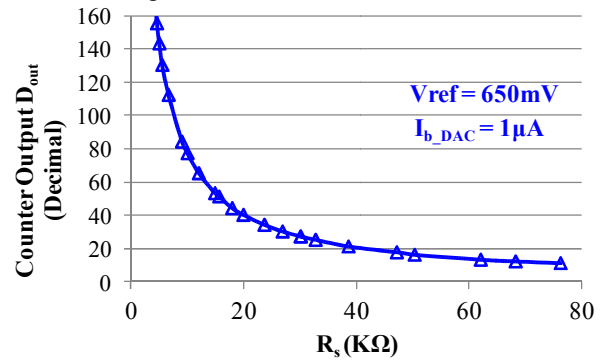


Figure 8. Measurement results of  $D_{\text{out}}$  versus  $R_s$  at  $V_{\text{ref}} = 650\text{mV}$  and  $R_s$  varied from  $2.5\text{K}\Omega$  to  $80\text{K}\Omega$

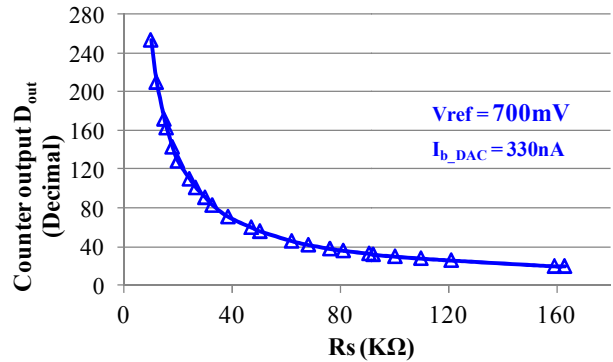


Figure 9. Measurement results of  $D_{\text{out}}$  versus  $R_s$  at  $V_{\text{ref}} = 700\text{mV}$  and  $R_s$  varied from  $10\text{K}\Omega$  to  $165\text{K}\Omega$

TABLE I. CHIP SPECIFICATIONS

Specification	Measurement Result
Process	TSMC $0.18\mu\text{m}$ CMOS 1P6M
Power Supply	1V
Power Dissipation	$86.41\mu\text{W}$
Adaptive resistance range	$10\text{K}\Omega\sim 500\text{K}\Omega$
Chip size ( $\text{mm}^2$ )	$0.72623 \times 0.6541$

Fig. 10 shows the setup and the experimental steps. A FIGARO<sup>®</sup> TGS-2610 gas sensor was placed into a 4-neck bottle chamber, and a motor was used to flush the chamber. The condition of the interface circuit was set to be the same to the chip measurement in Fig. 8. Fig. 11 shows the gas experimental results of  $D_{out}$  and  $\Delta D_{out}/D_{out2}(=\Delta R/R_1)$ . At  $t=0$ sec, the UP/DN counter was reset and the circuit was in the adaptive mode. In 0~20 sec,  $V_s$  tracked to  $V_{ref}$ , and then the circuit entered into sensing mode. At  $t=20$  sec, 3 $\mu$ l methanol was injected into the 4-neck bottle chamber. In 20~230 sec, the sensor was exposed to methanol vapor, and the sensor resistance decreased and  $D_{out}$  increased. At  $t=230$  sec, the gas was flushed out, the sensor resistance increased and  $D_{out}$  decreased. Another reset signal should be given before next gas experiment. According to the above experiment results,  $R_s$  could be obtained from equation (4) and Fig. 8. Consequently, the ADC-free adaptive interface circuit worked successfully as expected. In the future, we plan to deposit proper sensing materials on the interdigitated electrodes, and then realize the same gas experiment.

#### IV. CONCLUSION

We proposed an ADC-free adaptive interface circuit which  $V_s$  could automatically track to  $V_{ref}$  and cancel the baseline drift. The sensor signal was converted into digital code, so it could be directly delivered to the digital processing stage of recognition system without an ADC, which was area efficient. The percentage change of resistance  $\Delta R_s/R_1$  could be obtained from  $\Delta D_{out}/D_{out2}$ . For circuit verification, the adaptive interface circuit has been connected with a metal oxide gas sensor, FIGARO<sup>®</sup> TGS-2610, and the gas experiment has been executed with methanol vapor. The chip test and gas experiment showed the ability to cancel baseline drift and readout the gas sensor with low power (86.41 $\mu$ W). The circuit was fabricated by TSMC 0.18 $\mu$ m process and operated under 1V supply voltage, which is suitable for a portable E-nose system. In the future, sensing materials will be deposited on the interdigitated electrode to form the on-chip integrated gas sensors, and multi-channel interface circuit for a sensor array and microcontroller will be integrated on the same chip to implement the E-nose SoC.

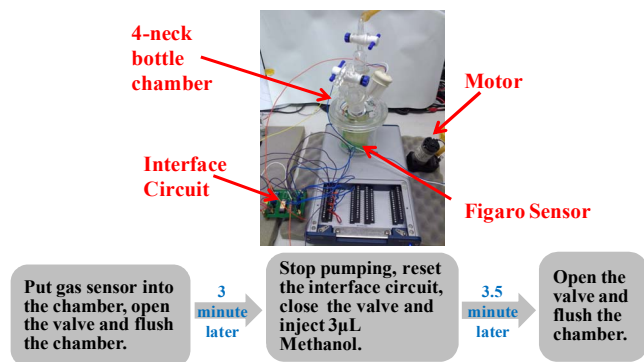


Figure 10. The gas experiment environment and the experiment steps.

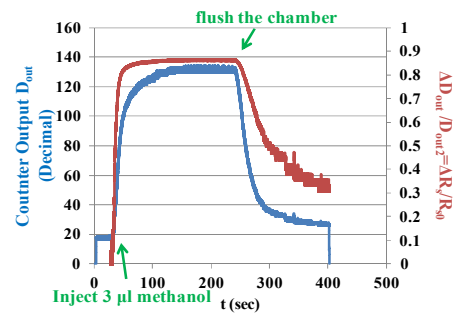


Figure 11. The gas experiment result of  $D_{out}$ ,  $\Delta D_{out}/D_{out2}$  and  $\Delta R/R_1$ .

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